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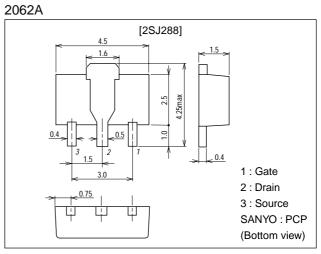
# **Ultrahigh-Speed Switching Applications**

### Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.

## **Package Dimensions**

unit:mm



# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

| Parameter                   | Symbol           | Conditions   | Ratings     | Unit |
|-----------------------------|------------------|--|-------------|------|
| Drain-to-Source Voltage     | V <sub>DSS</sub> |  | -60         | V    |
| Gate-to-Source Voltage      | VGSS             |  | ±15         | V    |
| Drain Current (DC)          | ۱ <sub>D</sub>   |  | -500        | mA   |
| Drain Current (Pulse)       | I <sub>DP</sub>  | PW≤10µs, duty cycle≤1%                               | -2          | A    |
| Allowable Power Dissipation | P_               | Tc=25°C  | 3.5         | W    |
|                             | PD               | Mounted on ceramic board (250mm <sup>2</sup> ×0.8mm) | 1.3         | W    |
| Channel Temperature         | Tch              |  | 150         | °C   |
| Storage Temperature         | Tstg             |  | -55 to +150 | °C   |

#### **Electrical Characteristics at Ta = 25°C**

| Parameter                                  | Symbol              | Conditions                                    | Ratings |     |      | Unit |
|--|---------------------|---|---------|-----|------|------|
|  |                     |   | min     | typ | max  | Unit |
| Drain-to-Source Breakdown Voltage          | V(BR)DSS            | I <sub>D</sub> =-1mA, V <sub>GS</sub> =0      | -60     |     |      | V    |
| Zero-Gate Voltage Drain Current            | IDSS                | V <sub>DS</sub> =-60V, V <sub>GS</sub> =0     |         |     | -100 | μΑ   |
| Gate-to-Source Leakage Current             | IGSS                | V <sub>GS</sub> =±12V, V <sub>DS</sub> =0     |         |     | ±10  | μΑ   |
| Cutoff Voltage                             | VGS(off)            | $V_{DS}$ =-10V, I <sub>D</sub> =-1mA          | -1.0    |     | -2.0 | V    |
| Forward Transfer Admittance                | yfs                 | V <sub>DS</sub> =-10V, I <sub>D</sub> =-250mA | 240     | 400 |      | mS   |
| Static Drain-to-Source ON-State Resistance | R <sub>DS(on)</sub> | I <sub>D</sub> =-250mA, V <sub>GS</sub> =-10V |         | 2.2 | 3.0  | Ω    |
|  | R <sub>DS(on)</sub> | I <sub>D</sub> =-250mA, V <sub>GS</sub> =-4V  |         | 3.0 | 4.0  | Ω    |

Marking : JE

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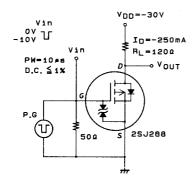
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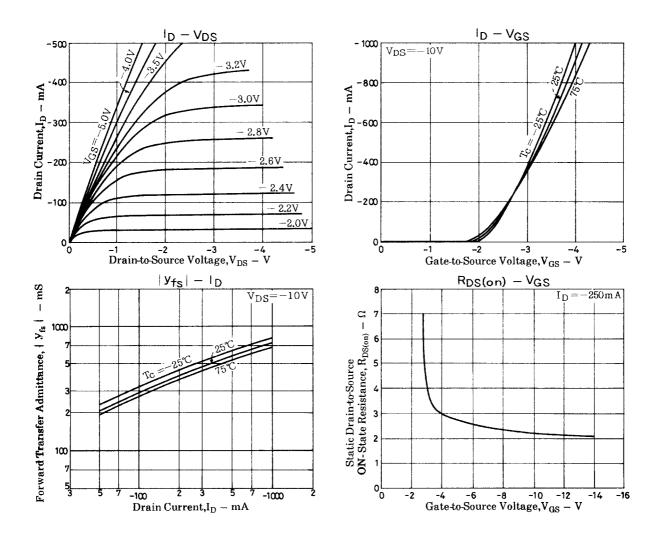
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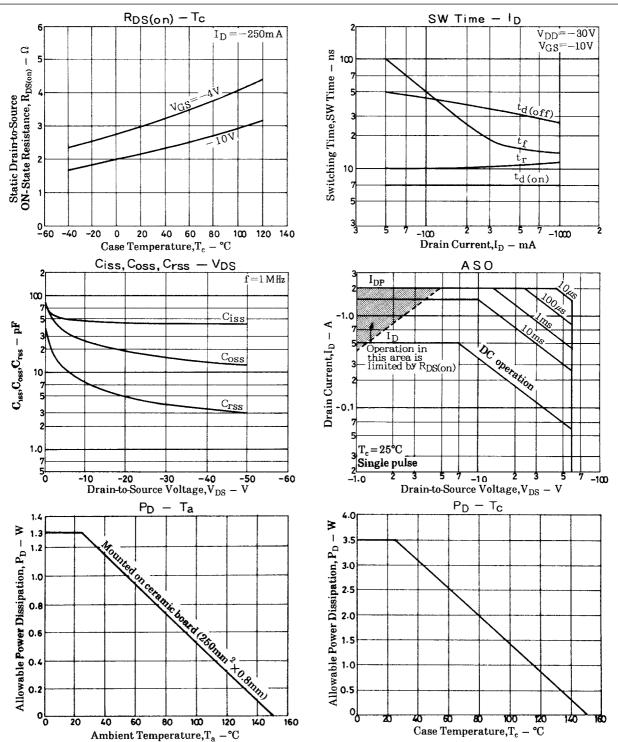
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| Parameter                    | Symbol              | Conditions                                 | Ratings |     |     | Unit |
|------------------------------|---------------------|--|---------|-----|-----|------|
|                              |                     |  | min     | typ | max | Unit |
| Input Capacitance            | Ciss                | V <sub>DS</sub> =–20V, f=1MHz              |         | 45  |     | pF   |
| Output Capacitance           | Coss                | V <sub>DS</sub> =–20V, f=1MHz              |         | 20  |     | pF   |
| Reverse Transfer Capacitance | Crss                | V <sub>DS</sub> =–20V, f=1MHz              |         | 5   |     | pF   |
| Turn-ON Delay Time           | <sup>t</sup> d(on)  | See specified Test Circuit                 |         | 7   |     | ns   |
| Rise Time                    | tr                  | See specified Test Circuit                 |         | 10  |     | ns   |
| Turn-OFF Delay Time          | <sup>t</sup> d(off) | See specified Test Circuit                 |         | 35  |     | ns   |
| Fall Time                    | t <sub>f</sub>      | See specified Test Circuit                 |         | 20  |     | ns   |
| Diode Forward Voltage        | V <sub>SD</sub>     | I <sub>S</sub> =-500mA, V <sub>GS</sub> =0 |         | -1  |     | V    |

#### **Switching Time Test Circuit**







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